(11) **EP 3 511 985 A1**

(12)

EUROPEAN PATENT APPLICATION

published in accordance with Art. 153(4) EPC

(43) Date of publication: 17.07.2019 Bulletin 2019/29

(21) Application number: 17849015.7

(22) Date of filing: 29.08.2017

(51) Int Cl.: H01L 27/15 (2006.01) H01L 29/786 (2006.01)

H01L 33/02 (2010.01)

(86) International application number: PCT/KR2017/009405

(87) International publication number: WO 2018/048131 (15.03.2018 Gazette 2018/11)

(84) Designated Contracting States:

AL AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC MK MT NL NO PL PT RO RS SE SI SK SM TR

Designated Extension States:

BAME

Designated Validation States:

MA MD

(30) Priority: 12.09.2016 US 201662393515 P

(71) Applicant: Seoul Semiconductor Co., Ltd. Ansan-si, Gyeonggi-do 15429 (KR)

(72) Inventors:

 TAKEYA, Motonobu Ansan-si Gyeonggi-do 15429 (KR)

 KIM, Young Hyun Ansan-si Gyeonggi-do 15429 (KR)

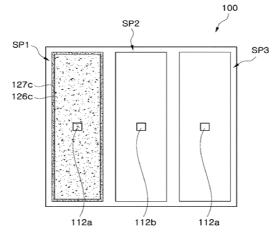
(74) Representative: Stolmár & Partner Patentanwälte PartG mbB Blumenstraße 17 80331 München (DE)

(54) **DISPLAY DEVICE**

(57) Disclosed is a display apparatus. The display apparatus includes: a light emitting part including a plurality of light emitting diodes regularly arranged thereon; a TFT panel part including a plurality of TFTs driving the plurality of light emitting diodes; and a light conversion part converting light emitted from the light emitting part, wherein the light emitting part and the TFT panel part are coupled to each other so as to face each other at one side thereof such that the light emitting diodes are electrically connected to the TFTs, respectively; the plurality of light emitting diodes includes at least one first light

emitting diode and at least one second light emitting diode; the light conversion part emits red light through conversion of light emitted from the at least one first light emitting diode; and the at least one second light emitting diode emits green light to the outside. The display apparatus employs micro-light emitting diodes formed of nitride semiconductors to realize high resolution, low power consumption and high efficiency. Accordingly, the display apparatus can be applied to various apparatuses including a wearable apparatus.





EP 3 511 985 A

Description

[Technical Field]

⁵ **[0001]** Exemplary embodiments of the present disclosure relate to a display apparatus, and more particularly, to a display apparatus using micro-light emitting diodes.

[Background Art]

15

20

30

35

[0002] A light emitting diode refers to an inorganic semiconductor device that emits light through recombination of electrons and holes. In recent years, light emitting diodes have been used in various fields including displays, automobile lamps, general lighting, and the like, and application fields of such light emitting diodes have expanded.

[0003] Light emitting diodes have various advantages such as long lifespan, low power consumption, and rapid response. Thus, a light emitting device using a light emitting diode can be used as a light source in various fields.

[0004] Recently, smart TVs or monitors realize colors using a thin film transistor liquid crystal display (TFT-LCD) panel and use light emitting diodes as a light source for a backlight unit for color realization. In addition, a display apparatus is often manufactured using organic light emitting diodes (OLEDs).

[0005] As a backlight light source of a TFT-LCD panel, one LED is used to supply light to many pixels of the TFT-LCD panel. In this structure, since the backlight light source must be kept on regardless of colors displayed on a screen of the TFT-LCD panel, the TFT-LCD panel suffers from constant power consumption regardless of brightness of a displayed screen

[0006] In addition, although power consumption of an OLED display apparatus has been continuously reduced due to technological development, OLEDs still has much higher power consumption than LEDs formed of inorganic semi-conductors and thus has low efficiency.

[0007] Moreover, a PM drive type OLED display apparatus can suffer from deterioration in response speed upon pulse amplitude modulation (PAM) of the OLED having large capacitance. In addition, the PM drive type OLED display apparatus can suffer from deterioration in lifespan upon high current driving through pulse width modulation (PWM) for realizing a low duty ratio.

[0008] Moreover, an AM driving type OLED display apparatus requires connection of TFTs for each pixel, thereby causing increase in manufacturing costs and nonuniform brightness according to characteristics of TFTs.

[Prior Literature]

[Patent Document]

[0009] Japanese Unexamined Patent Publication No. 2015-500562 (2015.01.05)

[Disclosure]

40 [Technical Problem]

[0010] Exemplary embodiments of the present disclosure provide a display apparatus using micro-light emitting diodes having low power consumption to be applicable to a wearable apparatus, a smartphone or a TV.

45 [Technical Solution]

[0011] In accordance with one aspect of the present disclosure, a display apparatus includes: a light emitting part including a plurality of light emitting diodes regularly arranged thereon; a TFT panel part including a plurality of TFTs driving the plurality of light emitting diodes; and a light conversion part converting light emitted from the light emitting part, wherein the light emitting part and the TFT panel part are coupled to each other so as to face each other at one side thereof such that the light emitting diodes are electrically connected to the TFTs, respectively; the plurality of light emitting diodes includes at least one first light emitting diode and at least one second light emitting diode; the light conversion part emits red light through wavelength conversion of light emitted from the at least one first light emitting diode; and the at least one second light emitting diode emits green light.

[Advantageous Effects]

[0012] According to exemplary embodiments, the display apparatus employs micro-light emitting diodes formed of

2

55

50

nitride semiconductors to realize high resolution, low power consumption and high efficiency. Accordingly, the display apparatus can be applied to various apparatuses including a wearable apparatus.

[0013] In addition, the display apparatus is manufactured using blue light emitting diodes and green light emitting diodes, thereby improving efficiency while reducing manufacturing costs.

[0014] Further, in the display apparatus according to exemplary embodiments, a subpixel emitting red light has a larger area than subpixels emitting blue light and green light. Thus, the display apparatus increases intensity of red light emitted through phosphors such that blue light, green light and red light emitted from one pixel can have uniform intensity.

[Description of Drawings]

[0015]

- FIG. 1 is a plan view of a pixel of a display apparatus according to a first exemplary embodiment of the present disclosure.
- FIG. 2 is a cross-sectional view of the pixel of the display apparatus according to the first exemplary embodiment of the present disclosure.
 - FIG. 3 is a cross-sectional view of a pixel of a display apparatus according to a second exemplary embodiment of the present disclosure.
 - FIG. 4 is a plan view of a pixel of a display apparatus according to a third exemplary embodiment of the present disclosure.
 - FIG. 5 is a cross-sectional view of the pixel of the display apparatus according to the third exemplary embodiment of the present disclosure.
 - FIG. 6 is a cross-sectional view of a pixel of a display apparatus according to a fourth exemplary embodiment of the present disclosure.
- FIG. 7 is a cross-sectional view of a pixel of a display apparatus according to a fifth exemplary embodiment of the present disclosure.
 - FIG. 8 is a plan of a pixel of a display apparatus according to a sixth exemplary embodiment of the present disclosure.
 - FIG. 9 is a cross-sectional view of the pixel of the display apparatus according to the sixth exemplary embodiment of the present disclosure.
 - FIG. 10 is a cross-sectional view of a pixel of a display apparatus according to a seventh exemplary embodiment of the present disclosure.
 - FIG. 11 is a plan view of a pixel of a display apparatus according to an eighth exemplary embodiment of the present disclosure.
 - FIG. 12 is cross-sectional views taken along lines of FIG. 11.

[Best Mode]

[0016] In accordance with one aspect of the present disclosure, a display apparatus includes; a light emitting part including a plurality of light emitting diodes regularly arranged thereon; a TFT panel part including a plurality of TFTs driving the plurality of light emitting diodes; and a light conversion part converting light emitted from the light emitting part, wherein the light emitting part and the TFT panel part are coupled to each other so as to face each other at one side thereof such that the light emitting diodes are electrically connected to the TFTs, respectively; the plurality of light emitting diodes includes at least one first light emitting diode and at least one second light emitting diode; the light conversion part emits red light through wavelength conversion of light emitted from the at least one first light emitting diode; and the at least one second light emitting diode emits green light.

[0017] The at least one first light emitting diode may be a blue light emitting diode or a UV light emitting diode, and the light conversion part may include a red phosphor layer emitting red light through wavelength conversion of light emitted from the at least one first light emitting diode.

[0018] The at least one first light emitting diode may be disposed in a first subpixel, the at least one second light emitting diode may be disposed in a second subpixel, and the first subpixel may have a larger size than the second

[0019] The plurality of light emitting diodes may further include at least one third light emitting diode disposed in a third subpixel. The first subpixel may have a larger size than the third subpixel and may be disposed on a side surface on which the second and third subpixels are arranged in line.

[0020] The plurality of light emitting diodes may further include at least one third light emitting diode. In this exemplary embodiment, the at least one second light emitting diode may be a green light emitting diode and the at least one third light emitting diode may be a blue light emitting diode.

[0021] The plurality of light emitting diodes may further include at least one third light emitting diode. In this exemplary

3

10

20

15

25

35

30

45

40

50

55

embodiment, the at least one third light emitting diode may be a UV light emitting diode and the light conversion part may further include a blue phosphor layer emitting blue light through wavelength conversion of UV light emitted from the UV light emitting diode.

[0022] The plurality of light emitting diodes may further include at least one fourth light emitting diode. In this exemplary embodiment, the at least one fourth light emitting diode may be a blue light emitting diode and the light conversion part may further include a white phosphor layer emitting white light through wavelength conversion of light emitted from the fourth light emitting diode.

[0023] The first to fourth light emitting diodes may be disposed in first to fourth subpixels, respectively, and the first and fourth subpixels may have larger sizes than the second and third subpixels.

[0024] The first and second subpixels may be disposed in one column, the third and fourth subpixels may be disposed in another column, and the first and fourth subpixels may be disposed in one row.

[0025] The light conversion part may include a color filter blocking light of other wavelengths excluding red light.

[0026] The light emitting part may include a plurality of light emitting diodes; a transparent electrode disposed on the plurality of light emitting diodes and electrically connected to the plurality of light emitting diodes; a connection electrode disposed under the plurality of light emitting diodes and electrically connected to the plurality of light emitting diodes; and a blocking portions disposed between the plurality of light emitting diodes and electrically connected to the transparent electrodes.

[0027] Each of the plurality of light emitting diodes may include an n-type semiconductor layer; a p-type semiconductor layer; and an active layer interposed between the n-type semiconductor layer and the p-type semiconductor layer.

[0028] The light conversion part may include a phosphor layer including a red phosphor layer emitting red light through wavelength conversion of light emitted from the at least one first light emitting diode; and a protective substrate disposed on the phosphor layer.

[0029] The phosphor layer may further include a transparent layer through which light emitted from the second light emitting diode passes without wavelength conversion.

[0030] The display apparatus may further include a color filter disposed between the phosphor layer and the protective substrate and blocking light emitted from the phosphor layer and having a certain wavelength.

[0031] Exemplary embodiments of the present disclosure will be described in detail with reference to the accompanying drawings.

[0032] FIG. 1 is a plan view of a pixel of a display apparatus according to a first exemplary embodiment of the present disclosure and FIG. 2 is a cross-sectional view of the pixel of the display apparatus according to the first exemplary embodiment of the present disclosure.

30

35

40

45

50

55

[0033] Referring to FIG. 1 and FIG. 2, the display apparatus 100 according to the first exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123.

[0034] The light emitting part 111 includes blue light emitting diodes 112a, green light emitting diodes 112b, transparent electrodes 116, blocking portions 118, and first connection electrodes 122.

[0035] The blue light emitting diode 112a and the green light emitting diode 112b are provided in plural and arranged at regular intervals. For example, a plurality of blue light emitting diodes 112a and a plurality of green light emitting diodes 112b may be arranged at constant intervals in rows and columns. With this arrangement of the plurality of blue light emitting diodes 112a and the plurality of green light emitting diodes 112b, a plurality of pixels may be formed. Referring to FIG. 1, in this exemplary embodiment, one pixel may be composed of three subpixels SP1, SP2, SP3, in which one green light emitting diode 112b is disposed in a second subpixel SP2 and two blue light emitting diodes 112a are disposed in the remaining two subpixels SP1, SP2, respectively. Although the following description will be given of the structure wherein one light emitting diode 112a or 112b is disposed in one of the subpixels SP1, SP2, SP3, it should be understood that two or more light emitting diodes may be provided to one subpixel SP1, SP2 or SP3, as needed.

[0036] In this exemplary embodiment, each of the subpixels SP1, SP2, SP3 may have a larger size than the light emitting diode 112a or 112b disposed in the corresponding subpixel SP1, SP2 or SP3. In addition, the subpixels SP1, SP2, SP3 may have the same size.

[0037] In the display apparatus 100 according to this exemplary embodiment, when power is applied to each of the light emitting diodes 112a, 112b, each of the light emitting diodes 112a, 112b can be turned on or off by power applied thereto and the light emitting part 111 coupled to the light conversion part 123 can be driven. That is, light emitted from the light emitting part 111 is converted into blue light, green light and red light while passing through the light conversion part 123, whereby blue light, green light and red light can be discharged from the display apparatus. Accordingly, the light emitting diode part 110 of the display apparatus 100 can be driven without a separate LCD.

[0038] In this exemplary embodiment, each of the blue light emitting diode 112a and the green light emitting diode 112b may include an n-type semiconductor layer 23, an active layer 25, and a p-type semiconductor layer 27. Here, each of the n-type semiconductor layer 23, the active layer 25 and the p-type semiconductor layer 27 may include Group III-V based compound semiconductors. By way of example, these semiconductor layers may include nitride semicon-

ductors such as (Al, Ga, In)N. In other exemplary embodiments, locations of the n-type semiconductor layer 23 and the p-type semiconductor layer 27 can be interchanged.

[0039] The n-type semiconductor layer 23 may be a conductive semiconductor layer including an n-type dopant (for example, Si) and the p-type semiconductor layer 27 may be a conductive semiconductor layer including a p-type dopant (for example, Mg). The active layer 25 is interposed between the n-type semiconductor layer 23 and the p-type semiconductor layer 27, and may have a multi-quantum well (MQW) structure. The composition of the active layer 25 may be determined so as to emit light having a desired peak wavelength. With this structure, the blue light emitting diode 112a can emit blue light having a peak wavelength of, for example, 430 nm to 470 nm, and the green light emitting diode 112b can emit green light having a peak wavelength of, for example, 510 nm to 550 nm.

[0040] In this exemplary embodiment, each of the blue light emitting diode 112a and the green light emitting diode 112b may have the shape of a vertical type light emitting diode. In this structure, an n-type electrode may be formed on an outer surface of the n-type semiconductor layer 23 and a p-type electrode may be formed on an outer surface of the p-type semiconductor layer 27. The following description will be given of the structure wherein the n-type electrode and the p-type electrode are omitted. In other exemplary embodiments, at least one of the n-type electrode and the p-type electrode may be provided in plural.

[0041] The transparent electrode 116 may be electrically connected to the n-type semiconductor layer 23 of the blue light emitting diode 112a and the green light emitting diode 112b, and may be electrically connected to the blocking portion 118. The transparent electrode 116 may have as thin a thickness as possible and may be transparent to allow light emitted from the blue light emitting diode 112a and the green light emitting diode 112b to reach the light conversion part 123 therethrough. For example, the transparent electrode 116 may be formed of ITO.

20

30

35

45

50

55

[0042] The blocking portions 118 are disposed to define a region for one subpixel and may be formed of a material exhibiting electrical conductivity. Accordingly, a region for each subpixel can be set by the blocking portions 118 and each of the blue light emitting diode 112a and the green light emitting diode 112b can be disposed in each of the subpixels SP1, SP2, SP3.

[0043] With this arrangement of the blocking portion 118, light emitted from one subpixel can be prevented from reaching other subpixels adjacent thereto. In this exemplary embodiment, a side surface of the blocking portion 118 may be a reflective surface capable of reflecting light emitted from the blue light emitting diode 112a or the green light emitting diode 112b. In addition, although the side surface of the blocking portion 118 is shown as being a vertical surface, the side surface of the blocking portion 118 may be an inclined surface. Accordingly, light emitted from each of the light emitting diodes 112a, 112b can be reflected by the blocking portion 118 to be discharged in an upward direction of the subpixel.

[0044] The blocking portions 118 may be electrically connected to the TFT panel part 130 such that the TFT panel part 130 can be electrically connected to the n-type semiconductor layer 23 through the transparent electrodes 116 and the blocking portions 118.

[0045] The first connection electrodes 122 may be provided in plural such that one first connection electrode 122 is provided to each of the subpixels SP1, SP2, SP3 to be electrically connected to the p-type semiconductor layer 27 of the blue light emitting diode 112a and the green light emitting diode 112b. Accordingly, the TFT panel part 130 can be electrically connected to the p-type semiconductor layer 27 through the first connection electrodes 122.

[0046] In this exemplary embodiment, the light conversion part 123 includes a phosphor layer 126, a color filter 127, and a protective substrate 128.

[0047] The phosphor layer 126 may be disposed on the protective substrate 128 and include a red phosphor layer 126c and a transparent layer 126e. In addition, a blocking layer 126d may be interposed between the red phosphor layer 126c and the transparent layer 126e. The blocking layer 126d can prevent mixture of light by preventing light having entered the red phosphor layer 126c or the transparent layer 126e from entering another red phosphor layer 126c or transparent layer 126e adjacent thereto.

[0048] As shown in FIG. 1 and FIG. 2, the red phosphor layer 126c is disposed in a region corresponding to a location at which one of two blue light emitting diodes 112a is disposed, and the transparent layer 126e is disposed in a region corresponding to a location at which each of the blue light emitting diode 112a and the green light emitting diode 112b is disposed. That is, the red phosphor layer 126c is disposed in the first subpixel SP1 and the transparent layer 126e is disposed in each of the second and third subpixels SP2, SP3. In this exemplary embodiment, the blocking layer 126d may be disposed between sections of the transparent layer 126e.

[0049] In this structure, green light and blue light emitted from the green light emitting diode 112b and the blue light emitting diode 112a disposed in the second and third subpixels SP2, SP3, on which the transparent layer 126e is disposed, can be discharged through the transparent layer 126e. In addition, light emitted from the blue light emitting diode 112a disposed in the first subpixel SP1 may be converted into red light through wavelength conversion of the red phosphor layer 126c disposed at the location corresponding to the blue light emitting diode 112a, whereby the red light can be discharged to the outside.

[0050] Further, in this exemplary embodiment, the color filter 127 may be interposed between the phosphor layer 126

and the protective substrate 128. The color filter 127 may include a red light portion 127c, a light blocking portion 127d, and a transparent portion 127e. In this exemplary embodiment, the color filter 127 may be formed in a film shape and can block light having passed through the color filter 127 excluding light of a certain wavelength.

[0051] That is, the red light portion 127c allows only red light to pass therethrough by blocking light having other wavelengths excluding red light. In this exemplary embodiment, the red light portion 127c is disposed at a location corresponding to the red phosphor layer 126c, so that light emitted from the red phosphor layer 126c enters the red light portion 127c. Thus, although most blue light emitted from the blue light emitting diode 112a is converted into red light through wavelength conversion of the red phosphor layer 126c, some fractions of the blue right can be discharged to the outside without wavelength conversion. Accordingly, the red light portion 127c serves to block the blue light not subjected to wavelength conversion while passing through the red phosphor layer 126c.

10

30

35

40

45

50

55

[0052] The transparent portion 127e may be disposed at a location corresponding to the transparent layer 126e of the phosphor layer 126. Accordingly, the transparent portion 127e allows blue light and green light having passed through the transparent layer 126e to be discharged therethrough without wavelength conversion. Further, the light blocking portion 127d is disposed between the red light portion 127c and the transparent portion 127e and can block light having passed though the red light portion 127c and the transparent portion 127e from being discharged to other sides.

[0053] The protective substrate 128 is disposed to contact the color filter 127 and can protect the color filter 127 from an external environment by preventing the color filter 127 from being directly exposed to the outside. In this exemplary embodiment, the protective substrate 128 may be formed of a transparent material so as to allow light to pass therethrough. [0054] The TFT panel part 130 is coupled to the light emitting part 111 and serves to supply power to the light emitting part 111. To this end, the TFT panel part 130 includes a panel substrate 132 and second connection electrodes 134. The TFT panel part 130 can control power supply to the light emitting part 111 to allow only some of the blue light emitting diode 112a and the green light emitting diode 112b in the light emitting part 111 to emit light and can control the intensity of light emitted from the light emitting diodes 112a, 112b.

[0055] The panel substrate 132 may have a TFT drive circuit therein. The TFT drive circuit may be a circuit for driving an active matrix (AM) or a circuit for driving a passive matrix (PM).

[0056] The second connection electrodes 134 are electrically connected to the TFT drive circuit of the panel substrate 132 and to the first connection electrodes 122 or the blocking portions 118 of the light emitting part 111. That is, the connection electrodes 134 may be provided in plural and may be separated from each other. Power supplied through the TFT drive circuit can be supplied to the blue light emitting diodes 112a and the green light emitting diodes 112b through the first connection electrodes 122 and the blocking portions 118 via the second connection electrodes 134. The second connection electrodes 134 may be covered by a separate protective substrate, which may include, for example, SiNx.

[0057] The anisotropic conductive film 150 serves to electrically connect the light emitting part 111 to the TFT panel part 130. The anisotropic conductive film 150 may include an adhesive organic insulating material and may contain conductive particles uniformly dispersed therein to achieve electrical connection. The anisotropic conductive film 150 exhibits electrical conductivity in the thickness direction thereof and insulating properties in the plane direction thereof. In addition, the anisotropic conductive film 150 exhibits adhesive properties. With this structure, the anisotropic conductive film 150 can bond the light emitting part 111 to the TFT panel part 130 such that the light emitting part 111 can be electrically connected to the TFT panel part 130 therethrough. Particularly, the anisotropic conductive film 150 may be advantageously used to connect ITO electrodes which are difficult to solder at high temperature.

[0058] As such, in the structure wherein the light emitting part 111 is coupled to the TFT panel part 130 via the anisotropic conductive film 150, each of the first connection electrode 122 and the blocking portion 118 can be electrically connected to the second connection electrode 134 via an electrode connection portion 152.

[0059] FIG. 3 is a cross-sectional view of a pixel of a display apparatus according to a second exemplary embodiment of the present disclosure.

[0060] Referring to FIG. 3, the display apparatus 100 according to the second exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the second exemplary embodiment, descriptions of the same components as the first exemplary embodiment will be omitted.

[0061] The light emitting part 111 includes blue light emitting diodes 112a, green light emitting diodes 112b, transparent electrodes 116, blocking portions 118, and first connection electrodes 122. The light conversion part 123 includes a phosphor layer 126 and a protective substrate 128.

[0062] Unlike the first exemplary embodiment, the light conversion part 123 of the display apparatus 100 according to this exemplary embodiment does not include the color filter 127. Accordingly, blue light emitted from one of two blue light emitting diodes 112a in the light emitting part 111 is converted into red light by wavelength conversion while passing through a red phosphor layer 126c of the phosphor layer 126, whereby the red light can be discharged to the outside through the protective substrate 128. That is, in this exemplary embodiment, the phosphor layer 126 includes the red phosphor layer 126c and a transparent layer 126e. As such, according to this exemplary embodiment, with the structure

wherein the light conversion part 123 includes the phosphor layer 126 and the protective substrate 128, the light conversion part 123 can be formed to a smaller thickness than that of the first exemplary embodiment.

[0063] Although the light emitting part employs the blue light emitting diodes 112a and the green light emitting diodes 112b in the first and second exemplary embodiments, the light emitting part may further include a UV light emitting diode 112d, as needed. The UV light emitting diode 112d may be disposed in the first subpixel SP1, in which the red phosphor layer 126c of the phosphor layer 126 is disposed, to replace the blue light emitting diode 112a of the first and second exemplary embodiments. Accordingly, UV light emitted from the UV light emitting diode 112d is converted into red light through wavelength conversion of the red phosphor layer 126c, whereby the red light can be discharged to the outside. In this exemplary embodiment, the UV light emitting diode 112d may emit UV light having a peak wavelength of, for example, 360 nm to 430 nm.

[0064] As in the first exemplary embodiment, the second and third subpixels SP2, SP3 are provided with the green light emitting diode 112b and the blue light emitting diode 112a, respectively.

10

30

35

40

45

50

55

[0065] FIG. 4 is a plan view of a pixel of a display apparatus according to a third exemplary embodiment of the present disclosure and FIG. 5 is a cross-sectional view of the pixel of the display apparatus according to the third exemplary embodiment of the present disclosure.

[0066] Referring to FIG. 4 and FIG. 5, the display apparatus 100 according to the third exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the third exemplary embodiment, descriptions of the same components as the first exemplary embodiment will be omitted.

[0067] The light emitting part 111 includes blue light emitting diodes 112a, green light emitting diodes 112b, transparent electrodes 116, blocking portions 118, and first connection electrodes 122. The light conversion part 123 includes a phosphor layer 126, a color filter 127, and a protective substrate 128.

[0068] Referring to FIG. 4, in this exemplary embodiment, one pixel includes three subpixels SP1, SP2, SP3, in which two blue light emitting diodes 112a and one green light emitting diode 112b are provided to the three subpixels SP1, SP2, SP3, respectively. Among the three subpixels SP1, SP2, SP3, a first subpixel SP1 has a larger size than second and third subpixels SP2, SP3. The second and third subpixels SP2, SP3 may have the same area. In this exemplary embodiment, although the first subpixel SP1 is shown as having an area about four times that of the second or third subpixel SP2, SP3, it should be understood that other implementations are possible and the size of the subpixels can be modified in various ways.

[0069] In this exemplary embodiment, the blue light emitting diodes 112a are disposed in the first and third subpixels SP1, SP3, respectively, and the green light emitting diode 112b is disposed in the second subpixel SP2.

[0070] As in the first exemplary embodiment, the light conversion part 123 includes a phosphor layer 126, a color filter 127, and a protective substrate 128. The phosphor layer 126 includes a red phosphor layer 126c, a blocking layer 126d, and a transparent layer 126e. The color filter 127 includes a red light portion 127c, a blocking portion 118, and a transparent portion 127e. In this exemplary embodiment, the red phosphor layer 126c is disposed in the first subpixel SP1 and the transparent layer 126e is disposed in the second and third subpixels SP2, SP3. Each of the red phosphor layer 126c and the transparent layer 126e may have a size corresponding to the size of the corresponding subpixel. Thus, the red phosphor layer 126c may have a larger size than the transparent layer 126e.

[0071] In the color filter 127, the red light portion 127c is disposed in the first subpixel SP1 and the transparent portion 127e is disposed in each of the second and third subpixels SP2, SP3. Each of the red light portion 127c and the transparent portion 127e may have a size corresponding to the size of the subpixel in which the red light portion 127c or the transparent portion 127e is disposed. Thus, the red light portion 127c may have a larger size than the transparent portion 127e.

[0072] As described above, the structure wherein the first subpixel SP1 has a larger size than the second and third subpixels SP2, SP3 results from the structure wherein the red phosphor layer 126c and the red light portion 127c are disposed only in the first subpixel SP1.

[0073] The second and third subpixels SP2, SP3 allow green light and blue light emitted from the green light emitting diode 112b and the blue light emitting diode 112a disposed therein to be discharged to the outside without wavelength conversion, respectively. On the other hand, in the first subpixel SP1, blue light emitted from the blue light emitting diode 112a is converted into red light through wavelength conversion of the red phosphor layer 126c, whereby the red light can be discharged to the outside. Here, the intensity of light emitted from the blue light emitting diode 112a can be reduced when discharged to the outside after passing through the red phosphor layer 126c and the red light portion 127c. [0074] According to this exemplary embodiment, since the first subpixel SP1, in which the red phosphor layer 126c and the red light portion 127c are disposed, has a larger size than the second and third subpixels SP2, SP3, light emitted from the subpixels SP1, SP2, SP3 can have the same intensity. Thus, the sizes of the first to third subpixels SP1, SP2, SP3 can be changed such that light emitted from the subpixels SP1, SP2, SP3 can have the same intensity.

[0075] According to this exemplary embodiment, the light emitting part 111, the light conversion part 123 and the TFT panel part 130 have the same structures as those of the first exemplary embodiment, and are different in size and location from those of the first exemplary embodiment in plan view.

[0076] FIG. 6 is a cross-sectional view of a pixel of a display apparatus according to a fourth exemplary embodiment of the present disclosure.

[0077] Referring to FIG. 6, the display apparatus 100 according to the fourth exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the fourth exemplary embodiment, descriptions of the same components as the first exemplary embodiment will be omitted.

[0078] The light emitting part 111 includes green light emitting diodes 112b, UV light emitting diodes 112d, transparent electrodes 116, blocking portions 118, and first connection electrodes 122. The light conversion part 123 includes a phosphor layer 126, a color filter 127, and a protective substrate 128.

[0079] Unlike the first exemplary embodiment, the display apparatus 100 according to this exemplary embodiment employs the UV light emitting diodes 112d instead of the blue light emitting diodes 112a. Thus, the UV light emitting diodes 112d are disposed in two subpixels, respectively, and the green light emitting diode 112b is disposed in one subpixel.

[0080] The phosphor layer 126 includes a blue phosphor layer 126a, a red phosphor layer 126c, and a transparent layer 126e. In addition, the phosphor layer 126 further includes a blocking layer 126d, which is disposed between the blue phosphor layer 126a and the red phosphor layer 126c and between the red phosphor layer 126c and the transparent layer 126e.

[0081] As in the first exemplary embodiment, the red phosphor layer 126c is disposed at a location corresponding to the first subpixel SP1 and emits red light through wavelength conversion of UV light emitted from the UV light emitting diode 112d. The blue phosphor layer 126a is disposed at a location corresponding to the third subpixel SP3 and emits blue light through wavelength conversion of UV light emitted from the UV light emitting diode 112d.

[0082] In addition, the color filter 127 includes a blue light portion, a red light portion 127c, and a transparent portion 127e. The color filter 127 further includes a light blocking portion 127d, which is disposed between the blue light portion and the red light portion 127c and between the red light portion 127c and the transparent portion 127e.

[0083] As in the first exemplary embodiment, the red light portion 127c is disposed at a location corresponding to the first subpixel SP1 and allows light emitted from the red phosphor layer 126c to pass therethrough such that only the red light can be discharged to the outside therethrough. The blue light portion is disposed at a location corresponding to the third subpixel SP3 and allows light emitted from the blue phosphor layer 126a to pass therethrough such that only the blue light can be discharged to the outside therethrough.

[0084] In this exemplary embodiment, the blue light portion allows only blue light to pass therethrough by blocking light of other wavelengths excluding blue light.

30

35

40

45

50

55

[0085] FIG. 7 is a cross-sectional view of a pixel of a display apparatus according to a fifth exemplary embodiment of the present disclosure.

[0086] Referring to FIG. 7, the display apparatus 100 according to the fifth exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the fifth exemplary embodiment, descriptions of the same components as the first and fourth exemplary embodiments will be omitted.

[0087] The light emitting part 111 includes green light emitting diodes 112b, UV light emitting diodes 112d, transparent electrodes 116, blocking portions 118, and first connection electrodes 122. The light conversion part 123 includes a phosphor layer 126 and a protective substrate 128.

[0088] Unlike the fourth exemplary embodiment, in the display apparatus 100 according to this exemplary embodiment, the light conversion part 123 does not include the color filter 127. Accordingly, UV light emitted from one of two UV light emitting diodes 112d in the light emitting part 111 is converted into red light through wavelength conversion of a red phosphor layer 126c of the phosphor layer 126, whereby the red light can be discharged to the outside through the protective substrate 128. In addition, UV light emitted from the other UV light emitting diode 112d is converted into blue light through wavelength conversion of a blue phosphor layer 126a of the phosphor layer 126, whereby the blue light can be discharged to the outside through the protective substrate 128.

[0089] That is, as in the fourth exemplary embodiment, the phosphor layer 126 according to this exemplary embodiment includes the blue phosphor layer 126a, the red phosphor layer 126c, and the transparent layer 126e. As such, in this exemplary embodiment, with the structure wherein the light conversion part 123 includes the phosphor layer 126 and the protective substrate 128, the light conversion part 123 can be formed to a smaller thickness than that of the fourth exemplary embodiment.

[0090] FIG. 8 is a plan view of a pixel of a display apparatus according to a sixth exemplary embodiment of the present disclosure and FIG. 9 is a cross-sectional view of the pixel of the display apparatus according to the sixth exemplary embodiment of the present disclosure.

[0091] Referring to FIG. 8 and FIG. 9, the display apparatus 100 according to the sixth exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the sixth exemplary embodiment,

descriptions of the same components as the first exemplary embodiment will be omitted.

10

25

30

35

40

45

50

55

[0092] In this exemplary embodiment, one pixel includes four subpixels SP1, SP2, SP3, SP4. Among the four subpixels SP1, SP2, SP3, SP4, blue light emitting diodes 112a may be provided to first, third and fourth subpixels SP1, SP3, SP4 may be provided with, respectively, and a green light emitting diode 112b may be provided to a second subpixel SP2.

[0093] In this exemplary embodiment, each of the subpixels SP1, SP2, SP3, SP4 may have a larger size than the light emitting diode 112a or 112b disposed in the corresponding subpixel SP1, SP2, SP3 or SP4. The subpixels SP1, SP2, SP3, SP4 may have the same size.

[0094] In this exemplary embodiment, the structure of the light emitting part 111 corresponding to one subpixel may be the same as that of the first exemplary embodiment. In addition, one subpixel may have the same size as that of the first exemplary embodiment or may have a smaller size than that of the first exemplary embodiment, as needed.

[0095] The light conversion part 123 includes a phosphor layer 126, a color filter 127, and a protective substrate 128. [0096] The phosphor layer 126 includes a red phosphor layer 126c, a transparent layer 126e, and a white phosphor layer 126f, and may further include a blocking layer 126d, which is disposed between the red phosphor layer 126c and the transparent layer 126e and between the transparent layer 126e.

[0097] The red phosphor layer 126c is disposed in the first subpixel SP1, in which the blue light emitting diode 112a is disposed. The transparent layer 126e is disposed in each of the second and third subpixels SP2, SP3, in which the green light emitting diode and the blue light emitting diode 112a are disposed, respectively, and the white phosphor layer 126f is disposed in the fourth subpixel SP4, in which the blue light emitting diode 112a is disposed.

[0098] The white phosphor layer 126f can emit white light through wavelength conversion of blue light emitted from the blue light emitting diode 112a disposed in the fourth subpixel SP4.

[0099] The color filter 127 may include a red light portion 127c, a light blocking portion 127d, and a transparent portion 127e. In this exemplary embodiment, the color filter 127 includes one red light portion 127c and three transparent portions 127e, and the light blocking portion 127d may be disposed between the red light portion 127c and the transparent portion 127e.

[0100] The red light portion 127c is disposed in the first subpixel SP1 and blocks light having passed through the red phosphor layer 126c excluding red light. The three transparent portions 127e are disposed in the second to fourth subpixels SP2, SP3, SP4, respectively. With this structure, green light emitted from the green light emitting diode 112b disposed in the second subpixel SP2 can be discharged to the outside through the transparent portion 127e and blue light emitted from the blue light emitting diode 112a disposed in the third subpixel SP3 can be discharged to the outside through the transparent portion 127e. In addition, white light emitted from the white phosphor layer 126f in the fourth subpixel SP4 can be discharged to the outside through the transparent portion 127e.

[0101] As such, the four subpixels SP1, SP2, SP3, SP4 constitute one pixel, whereby blue light, green light, red light, and white light can be discharged to the outside.

[0102] FIG. 10 is a plan view of a pixel of a display apparatus according to a seventh exemplary embodiment of the present disclosure.

[0103] Referring to FIG. 10, the display apparatus 100 according to the seventh exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the seventh exemplary embodiment, descriptions of the same components as the first and sixth exemplary embodiments will be omitted.

[0104] The light emitting part 111 includes blue light emitting diodes 112a, green light emitting diodes 112b, transparent electrodes 116, blocking portions 118, and first connection electrodes 122. The light conversion part 123 includes a phosphor layer 126 and a protective substrate 128.

[0105] Unlike the sixth exemplary embodiment, in the display apparatus 100 according to this exemplary embodiment, the light conversion part 123 does not include the color filter 127. Accordingly, blue light emitted from one of three blue light emitting diodes 112a in the light emitting part 111 is subjected to wavelength conversion while passing through a red phosphor layer 126c and blue light emitted from another blue light emitting diode is subjected to wavelength conversion while passing through the white phosphor layer 126f. That is, blue light emitted from the blue light emitting diode 112a disposed in the first subpixel SP1 is converted into red light through wavelength conversion of the red phosphor layer 126c, whereby the red light is discharged to the outside through the protective substrate 128, and blue light emitted from the blue light emitting diode 112a disposed in the fourth subpixel SP4 is converted into white light through wavelength conversion of the white phosphor layer 126f, whereby the white light is discharged to the outside through the protective substrate 128.

[0106] In addition, green light and blue light emitted from the green light emitting diode 112b and the blue light emitting diode 112a disposed in the second and third subpixels SP2, SP3, respectively, can be discharged to the outside through the transparent layer 126e and the protective substrate 128 without wavelength conversion.

[0107] As such, in this exemplary embodiment, the light conversion part 123 is composed of the phosphor layer 126 and the protective substrate 128, and thus can have a smaller thickness than the light conversion part 123 according to the sixth exemplary embodiment.

[0108] In addition, although the light emitting part employs the blue light emitting diodes 112a and the green light emitting diodes 112b in the sixth and seventh exemplary embodiments, the light emitting part may further include UV light emitting diodes 112d, as needed. The UV light emitting diode 112d may be disposed in each of the first subpixel SP1, in which the red phosphor layer 126c is disposed, and the fourth subpixel SP4, in which the white phosphor layer 126f is disposed. With this structure, UV light emitted from the UV light emitting diode 112d disposed in the first subpixel SP1 is converted into red light through wavelength conversion of the red phosphor layer 126c, whereby the red light can be discharged to the outside, and UV light emitted from the UV light emitting diode 112d disposed in the fourth subpixel SP4 is converted into white light through wavelength conversion of the white phosphor layer 126f, whereby the white light can be discharged to the outside.

[0109] As in the sixth and seventh exemplary embodiments, the second and third subpixels SP2, SP3 are provided with the green light emitting diode 112b and the blue light emitting diode 112a, respectively.

[0110] FIG. 11 is a plan view of a pixel of a display apparatus according to an eighth exemplary embodiment of the present disclosure, FIG. 12 (a) is a cross-sectional view taken along line A-A' of FIG. 11, and FIG. 12 (b) is a cross-sectional view taken along line B-B' of FIG. 11.

[0111] Referring to FIG. 11 and FIG. 12, the display apparatus 100 according to the eighth exemplary embodiment includes a light emitting diode part 110, a TFT panel part 130, and an anisotropic conductive film 150. The light emitting diode part 110 includes a light emitting part 111 and a light conversion part 123. In description of the eighth exemplary embodiment, descriptions of the same components as the first and sixth exemplary embodiments will be omitted.

[0112] Referring to FIG. 11, in this exemplary embodiment, one pixel includes four subpixels SP1, SP2, SP3, SP4. Among the four subpixels SP1, SP2, SP3, SP4, blue light emitting diodes 112a may be disposed in first, third and fourth subpixels SP1, SP3, SP4, respectively, and a green light emitting diode 112b may be disposed in a second subpixel SP2. [0113] Among the four subpixels SP1, SP2, SP3, SP4, the first and fourth subpixels SP1, SP4 may have a larger size than the second and third subpixels SP2, SP3. The first and fourth subpixels SP1, SP4 may have the same area, and the second and third subpixels SP2, SP3 may have the same area. Although the first and fourth subpixels SP1, SP4 are illustrated as having an area about two times that of the second and third subpixels SP2, SP3 in this exemplary embodiment, it should be understood that other implementations are possible and the size of the subpixels can be modified in various ways.

[0114] In this exemplary embodiment, blue light emitting diodes 112a are disposed in the first, third and fourth subpixels SP1, SP3, SP4, respectively, and a green light emitting diode 112b is disposed in the second subpixel SP2.

30

35

40

55

[0115] As in the sixth exemplary embodiment, the light conversion part 123 includes a phosphor layer 126, a color filter 127, and a protective substrate 128. The phosphor layer 126 includes a red phosphor layer 126c, a blocking layer 126d, a transparent layer 126e, and a white phosphor layer 126f. The color filter 127 includes a red light portion 127c, a blocking portion 118, and a transparent portion 127e. The red phosphor layer 126c is disposed in the first subpixel SP1 and the white phosphor layer 126f is disposed in the fourth subpixel SP4. In addition, the transparent layer 126e is disposed in each of the second and third subpixels SP2, SP3. Here, each of the red phosphor layer 126c, the transparent layer 126e and the white phosphor layer 126f has a larger size than the corresponding subpixel. Thus, each of the red phosphor layer 126c and the white phosphor layer 126f may have a larger size than the transparent layer 126e.

[0116] In the color filter 127, the red light portion 127c is disposed in the first subpixel SP1 and the transparent portion 127e is disposed in each of the second to fourth subpixels SP2, SP3, SP4. In this exemplary embodiment, the red light portion 127c disposed in the first subpixel SP1 and the transparent portion 127e disposed in the fourth subpixel SP4 may have a larger size than the transparent portions 127e disposed in the second and third subpixels SP2, SP3.

[0117] As such, the structure wherein the first and fourth subpixels SP1, SP4 have a larger size than the second and third subpixels SP2, SP3 results from the structure wherein the red phosphor layer 126c and the white phosphor layer 126f are disposed in the first and fourth subpixels SP1, SP4, respectively.

[0118] The second and third subpixels SP2, SP3 allow green light and blue light emitted from the green light emitting diode 112b and the blue light emitting diode 112a disposed therein to be discharged to the outside without wavelength conversion. On the other hand, in the first and fourth subpixels SP1, SP4, blue light emitted from the blue light emitting diodes 112a disposed therein is subjected to wavelength conversion in the red phosphor layer 126c and the white phosphor layer 126f. As a result, the intensity of light emitted through the red phosphor layer 126c and the white phosphor layer 126f can be reduced.

[0119] According to this exemplary embodiment, since the first and fourth subpixels SP1, SP4, in which the red phosphor layer 126c and the white phosphor layer 126f are disposed, have a larger size than the second and third subpixels SP2, SP3, light emitted from the subpixels can have the same intensity.

[0120] Here, the sizes of the first to fourth subpixels SP1, SP2, SP3, SP4 can be changed such that light emitted from the subpixels SP1, SP2, SP3, SP4 can have the same intensity.

[0121] Although some exemplary embodiments have been described herein, it should be understood by those skilled in the art that these embodiments are given by way of illustration only, and that various modifications, variations, and alterations can be made without departing from the spirit and scope of the invention. Therefore, the scope of the present

disclosure should be limited only by the accompanying claims and equivalents thereof.

*List of Reference Numerals

100: display apparatus
 110: light emitting diode part
 111: light emitting part

112a: blue light emitting diode

112b: green light emitting diode 112d: UV light emitting diode

23; n-type semiconductor layer 25: active layer

27: p-type semiconductor layer116: transparent electrode118: blocking portion122: first connection electrode

123: light conversion part

126: phosphor layer
126c: red phosphor layer
126c: red phosphor layer
126c: transparent layer
126f: white phosphor layer
127: color filter
127: red light portion

127: color filter127c: red light portion127d: light blocking portion127e: transparent portion

128: protective substrate

130: TFT panel part 132: panel substrate

134: second connection electrode

150: anisotropic conductive film 152: electrode connecting portion

SP1 to SP4: first to fourth subpixels

Claims

10

15

20

25

30

35

40

45

1. A display apparatus comprising:

a light emitting part comprising a plurality of light emitting diodes regularly arranged thereon;

a TFT panel part comprising a plurality of TFTs driving the plurality of light emitting diodes; and

a light conversion part converting light emitted from the light emitting part,

wherein the light emitting part and the TFT panel part are coupled to each other so as to face each other at one side thereof such that the light emitting diodes are electrically connected to the TFTs, respectively;

the plurality of light emitting diodes comprises at least one first light emitting diode and at least one second light emitting diode;

the light conversion part emits red light through wavelength conversion of light emitted from the at least one first light emitting diode; and

the at least one second light emitting diode emits green light.

- 2. The display apparatus according to claim 1, wherein the at least one first light emitting diode is a blue light emitting diode or a UV light emitting diode, and the light conversion part comprises a red phosphor layer emitting red light through wavelength conversion of light emitted from the at least one first light emitting diode.
- 3. The display apparatus according to claim 2, wherein the at least one first light emitting diode is disposed in a first subpixel and the at least one second light emitting diode is disposed in a second subpixel, the first subpixel having a larger size than the second subpixel.
- 4. The display apparatus according to claim 3, wherein the plurality of light emitting diodes further comprises at least one third light emitting diode disposed in a third subpixel,

the first subpixel having a larger size than the third subpixel and being disposed on a side surface on which the second and third subpixels are arranged in a line.

55 **5.** The display apparatus according to claim 2, wherein the plurality of light emitting diodes further comprises at least one third light emitting diode,

the at least one second light emitting diode is a green light emitting diode, and the at least one third light emitting diode is a blue light emitting diode.

- 6. The display apparatus according to claim 2, wherein the plurality of light emitting diodes further comprises at least one third light emitting diode, the at least one third light emitting diode being a UV light emitting diode, and the light conversion part further comprises a blue phosphor layer emitting blue light through wavelength conversion of UV light emitted from the UV light emitting diode.
- 7. The display apparatus according to claim 5, wherein the plurality of light emitting diodes further comprises at least one fourth light emitting diode, the at least one fourth light emitting diode being a blue light emitting diode, and the light conversion part further comprises a white phosphor layer emitting white light through wavelength conversion of light emitted from the fourth light emitting diode.
- 8. The display apparatus according to claim 7, wherein the first to fourth light emitting diode are disposed in first to fourth subpixels, respectively, the first and fourth subpixels having a larger size than the second and third subpixels.
- **9.** The display apparatus according to claim 8, wherein the first and second subpixels are disposed in one column, the third and fourth subpixels are disposed in another column, and the first and fourth subpixels are disposed in one row.
 - **10.** The display apparatus according to claim 1, wherein the light conversion part comprises a color filter blocking light of other wavelengths excluding red light.
 - **11.** The display apparatus according to claim 1, wherein the light emitting part comprises:
 - a plurality of light emitting diodes;

5

10

20

25

30

35

40

45

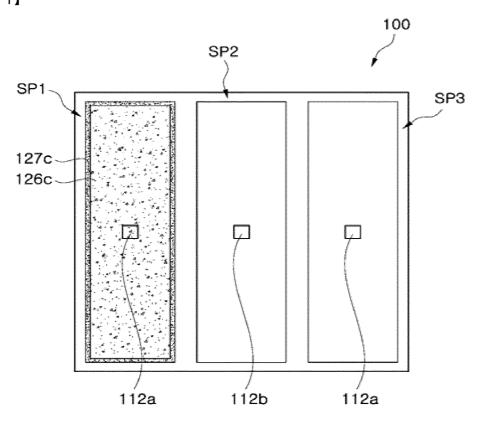
50

55

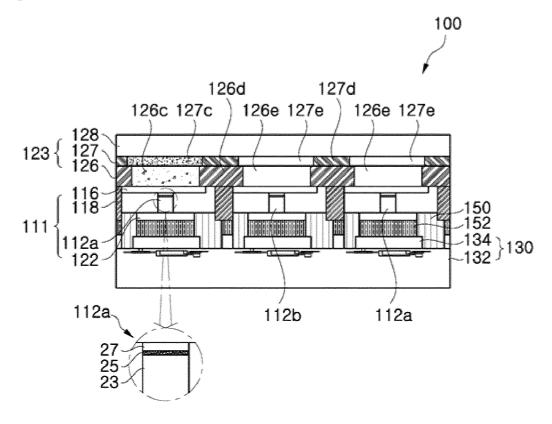
- a transparent electrode disposed on the plurality of light emitting diodes and electrically connected to the plurality of light emitting diodes;
- a connection electrode disposed under the plurality of light emitting diodes and electrically connected to the plurality of light emitting diodes; and
- a blocking portions disposed between the plurality of light emitting diodes and electrically connected to the transparent electrodes.
- 12. The display apparatus according to claim 11, wherein each of the plurality of light emitting diodes comprises:
 - an n-type semiconductor layer;
 - a p-type semiconductor layer; and
 - an active layer interposed between the n-type semiconductor layer and the p-type semiconductor layer.
- 13. The display apparatus according to claim 1, wherein the light conversion part comprises:
 - a phosphor layer comprising a red phosphor layer emitting red light through wavelength conversion of light emitted from the at least one first light emitting diode; and a protective substrate disposed on the phosphor layer.
- a protoctive substitute disposed on the phosphoritayer.
- **14.** The display apparatus according to claim 13, wherein the phosphor layer further comprises a transparent layer through which light emitted from the second light emitting diode passes without wavelength conversion.
- **15.** The display apparatus according to claim 13, further comprising: a color filter disposed between the phosphor layer and the protective substrate and blocking light emitted from the phosphor layer and having a certain wavelength.

12

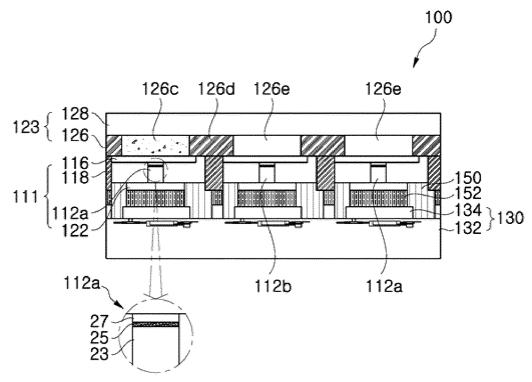
[FIG. 1]



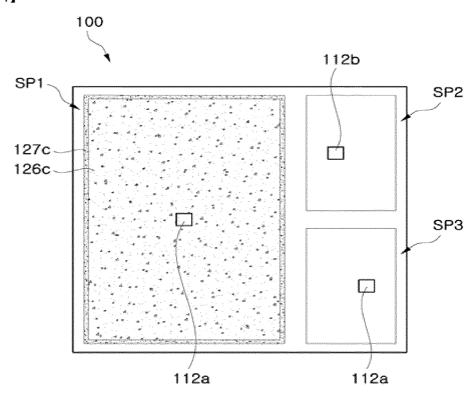
[FIG. 2]



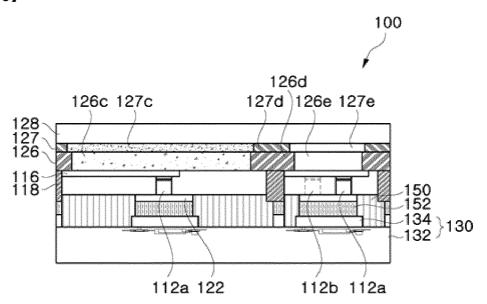
[FIG. 3]



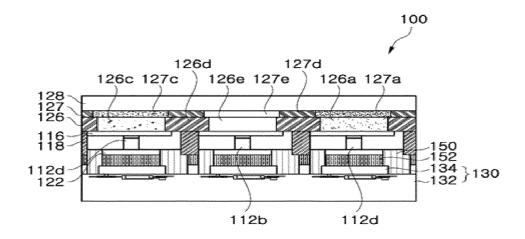
[FIG. 4]



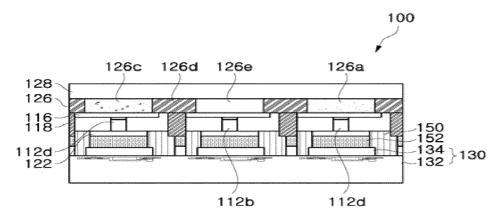
[FIG. 5]



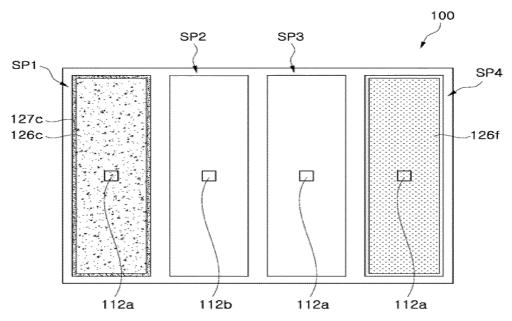
[FIG. 6]



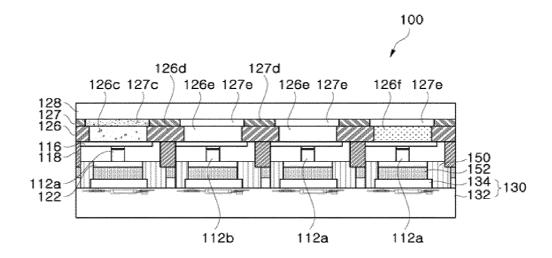
[FIG. 7]

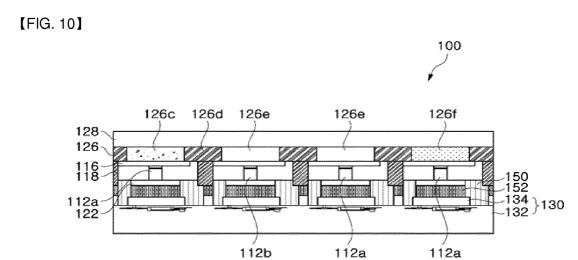


[FIG. 8]

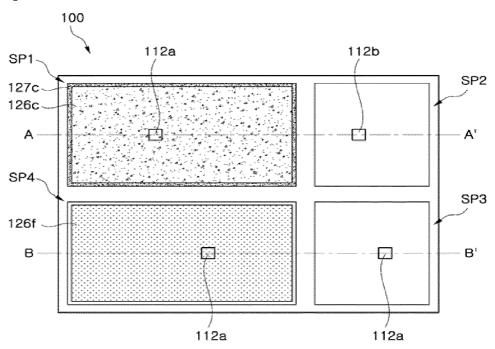


[FIG. 9]

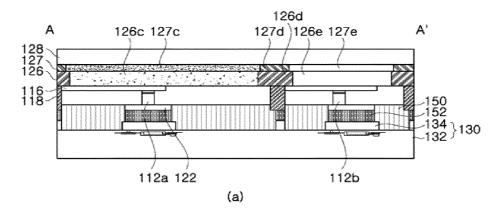


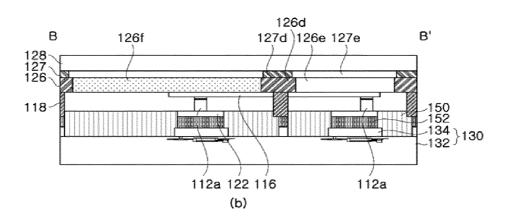


【FIG. 11】



[FIG. 12]





INTERNATIONAL SEARCH REPORT

International application No.

PCT/KR2017/009405

	A.	CLA:	SSIFIC	ATION C	OF SUBJEC	T MATTER
5	****					*****************************

10

15

20

25

30

35

40

45

50

55

H01L 27/15(2006.01)i, H01L 33/02(2010.01)i, H01L 29/786(2006.01)i

According to International Patent Classification (IPC) or to both national classification and IPC

FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

H01L 27/15; G09G 3/32; F21V 23/00; H01L 33/32; F21K 99/00; G09G 3/30; H01L 33/02; H01L 29/786

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Korean Utility models and applications for Utility models: IPC as above Japanese Utility models and applications for Utility models: IPC as above

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) eKOMPASS (KIPO internal) & Keywords: display, light-emitting diode, TFT, light converting part

DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	KR 10-2016-0010869 A (LUXVUE TECHNOLOGY CORPORATION) 28 January 2016 See paragraphs [0016]-[0091] and figures 1a-14b.	1-2,5-6,10,13,15
Y	See paragraphs (1907) [1907] met rightes in 170.	3-4,7-9,11-12,14
Y	US 2014-0014983 A1 (INTEMATIX CORPORATION) 16 January 2014 See paragraphs [0041]-[0044] and figures 4-5B.	3-4,8-9
Y	US 2014-0091993 A1 (NANO AND ADVANCED MATERIALS INSTITUTE LIMITED) 03 April 2014 See paragraphs [0052], [0055]-[0094] and figures 3-23.	7-9
Y	US 2010-0309101 A1 (KANEGAE, Arinobu et al.) 09 December 2010 See paragraphs [0127]-[0173] and figures 1-4H, 7.	11-12
Y	US 2015-0362165 A1 (HIPHOTON CO., LTD.) 17 December 2015 See paragraphs [0137]-[0166] and figures 25-40.	14

Ш	Further documents are listed in the continuation of Box C.	\boxtimes

See patent family annex.

- Special categories of cited documents:
- "A" document defining the general state of the art which is not considered to be of particular relevance
- earlier application or patent but published on or after the international "X" filing date "E"
- document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "L"
- document referring to an oral disclosure, use, exhibition or other
- document published prior to the international filing date but later than the priority date claimed
- later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention
- document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone
- document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art
- "&" document member of the same patent family Date of mailing of the international search report

Date of the actual completion of the international search 07 DECEMBER 2017 (07.12.2017)

07 DECEMBER 2017 (07.12.2017)

Name and mailing address of the ISA/KR

Korean Intellectual Property Office Government Complex-Daejeon, 189 Sconsa-ro, Daejeon 302-701, Republic of Korea Facsimile No. +82-42-481-8578

Authorized officer

Telephone No.

Form PCT/ISA/210 (second sheet) (January 2015)

INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No.

PCT/KR2017/009405

5	Patent document cited in search report	Publication date	Patent family member	Publication date
10	KR 10-2016-0010869 A	28/01/2016	CN 105339996 A EP 2997564 A1 EP 2997564 B1 JP 2016-523450 A KR 10-1704334 B1	17/02/2016 23/03/2016 06/09/2017 08/08/2016 07/02/2017
15			TW 201515260 A TW 1570953 B US 2014-0367633 A1 US 2015-0331285 A1 US 2017-0162553 A1 US 9111464 B2 US 9599857 B2	16/04/2015 11/02/2017 18/12/2014 19/11/2015 08/06/2017 18/08/2015 21/03/2017
20	US 20140014983 A1	16/01/2014	WO 2014-204694 A1 US 8994056 B2	24/12/2014 31/03/2015
25	US 2014-0091993 A1	03/04/2014	US 2011-0309378 A1 US 2012-0223875 A1 US 2014-0008667 A1 US 8557616 B2 US 8642363 B2 US 9041025 B2 US 9349911 B2 WO 2011-071559 A1	22/12/2011 06/09/2012 09/01/2014 15/10/2013 04/02/2014 26/05/2015 24/05/2016 16/06/2011
30	US 2010-0309101 A1	09/12/2010	US 08791881 B2 WO 2009-133680 A1	29/07/2014 05/11/2009
35	US 2015-0362165 A1	17/12/2015	US 09831387 B2 US 2015-0340346 A1 US 2016-0020353 A1 WO 2016-188505 A1 WO 2016-198686 A1 WO 2017-054696 A1	28/11/2017 26/11/2015 21/01/2016 01/12/2016 15/12/2016 06/04/2017
40				
45				
50				
55				

Form PCT/ISA/210 (patent family annex) (January 2015)

REFERENCES CITED IN THE DESCRIPTION

This list of references cited by the applicant is for the reader's convenience only. It does not form part of the European patent document. Even though great care has been taken in compiling the references, errors or omissions cannot be excluded and the EPO disclaims all liability in this regard.

Patent documents cited in the description

• JP 2015500562 A [0009]



专利名称(译)	显示装置		
公开(公告)号	EP3511985A4	公开(公告)日	2020-05-13
申请号	EP2017849015	申请日	2017-08-29
[标]申请(专利权)人(译)	首尔半导体股份有限公司		
申请(专利权)人(译)	首尔半导体CO.,LTD.		
当前申请(专利权)人(译)	首尔半导体CO.,LTD.		
[标]发明人	TAKEYA MOTONOBU KIM YOUNG HYUN		
发明人	TAKEYA, MOTONOBU KIM, YOUNG HYUN		
IPC分类号	H01L27/15 H01L33/02 H01L29/78	6	
CPC分类号	G02F1/133603 H01L25/0753 H01L33/504 H01L33/507 G02F1/133514 G02F1/133602 G02F2001 /133612 G02F2001/133614 H01L27/156		
优先权	62/393515 2016-09-12 US		
其他公开文献	EP3511985A1		
外部链接	Espacenet		

摘要(译)

公开了一种显示装置。 该显示装置包括:发光部分,其包括规则排列在其上的多个发光二极管;以及 TFT面板部,其包括驱动多个发光二极管的多个TFT。 发光部分和TFT面板部分彼此耦合,从而在其一侧彼此面对,从而使发光二极管电连接到发光部分。 TFT,分别; 多个发光二极管包括至少一个第一发光二极管和至少一个第二发光二极管。 所述光转换部通过转换从所述至少一个第一发光二极管发出的光而发出红光。 至少一个第二发光二极管向外部发射绿光。 该显示装置采用由氮化物半导体形成的微发光二极管以实现高分辨率,低功耗和高效率。 因此,显示设备可以应用于包括可穿戴设备的各种设备。